

Microsemi Corporation: CN19009

March 26, 2019

Customer Notification (CN): CN19009

Subject

RTG4 PLL Lock Stability

CN19009 is an early notification of an issue under investigation for the RTG4 FPGA family. There is no action required at this time. An amendment letter will be issued when the investigation is concluded.

Description of Change

RTG4 PLLs can experience loss of lock at high temperature after being initialized, via device power-up or PLL reset, at cold temperature. Once loss of lock happens, the PLL lock can be recovered by issuing a reset to the PLL.

The root cause of the PLL loss of lock has been identified. During RTG4 PLL initialization, a VCO gain setting is automatically chosen to ensure optimal operation. When the PLL is initialized at cold temperature, the automatically chosen VCO gain setting does not provide enough margin for the PLL to operate across the full military temperature range (-55 °C to 125 °C). Rising temperature normally reduces transistor performance, which slows down the VCO to the point where the PLL cannot remain locked. The PLL's VCO performance is similarly affected if the 3.3 V PLL power supply, VDDPLL, decreases after initial PLL reset.

The RTG4 junction temperature at power-up, or after PLL reset, determines the PLL operating temperature window before the loss of lock occurs. Resetting the PLL at higher temperatures selects a higher VCO gain, allowing the PLL to operate to a higher temperature.

Application Impact

1. Temperature ramping direction

The PLL loss of lock for the identified root cause has only been observed to occur at temperatures higher than the initial PLL reset temperature.

There is no loss of lock when operating at temperatures lower than the initial PLL reset temperature. (Characterized values for PLL reset temperature and VDDPLL impact will be published in a subsequent datasheet release and CN amendment).

2. Only certain RTG4 PLLs are impacted:

- Clock Conditioning Circuitry (CCC) PLLs available in the FPGA fabric
- FDDR PLLs used in the fabric DDR controllers
- SerDes SPLs being utilized in PCI Express (PCIe) and XAUI modes to synchronize data to the fabric clock rate

The SerDes PMA PLLs found in each SerDes lane are not impacted. The SerDes PMA PLLs do not use the same VCO gain setting at initialization as the SerDes SPLs. The SerDes External PCS (EPCS) mode requires that the user implement the serial protocol's PCS logic in the FPGA fabric. The EPCS mode only uses the SerDes PMA PLLs and is not impacted by this issue.

Workaround Under Evaluation

Microsemi is currently evaluating a workaround for this issue, taking into account any variation due to process, voltage, temperature, aging, and radiation effects. A future CN amendment will provide details on the workaround.

Products Affected by this Change

See [Appendix A](#).

Contact Information

If you have further questions about this subject, contact Microsemi's Technical Support department by using the Support Portal: <https://soc.microsemi.com/Portal/Default.aspx>.

Regards,

Microsemi Corporation

Any projected dates in this CN are based on the most current product information at the time this CN is being issued, but they may change due to unforeseen circumstances. For the latest schedule and any other information, please contact your local Microsemi Sales Office, the factory contact shown above, or your local distributor. This Product/Process Change Notification is confidential and proprietary information of Microsemi and is intended only for distribution by Microsemi to its customers, for customers' use only. It must not be copied or provided to any third party without Microsemi's prior written consent.

Appendix A

Table 1 • Products Affected by This Change

Microsemi Part Number	DLA SMD Number
RT4G150-CB1657PROTO	-
RT4G150-CG1657B	5962-1620801QXF
RT4G150-CG1657E	5962-1620805QXF
RT4G150-CG1657EV	-
RT4G150-CG1657V	5962-1620809VXF
RT4G150-CG1657PROTO	
RT4G150-CQ352B	-
RT4G150-CQ352E	-
RT4G150-CQ352EV	-
RT4G150-CQ352PROTO	-
RT4G150-LG1657B	5962-1620803QZC
RT4G150-LG1657E	5962-1620807QZC
RT4G150-LG1657EV	
RT4G150-LG1657V	5962-1620811VZC
RT4G150-LG1657PROTO	-
RT4G150-1CB1657PROTO	-
RT4G150-1CG1657B	5962-1620802QXF
RT4G150-1CG1657E	5962-1620806QXF
RT4G150-1CG1657EV	-
RT4G150-1CG1657V	5962-1620810VXF
RT4G150-1CG1657PROTO	-
RT4G150-1CQ352B	-
RT4G150-1CQ352E	-
RT4G150-1CQ352EV	-
RT4G150-1CQ352PROTO	
RT4G150-1LG1657B	5962-1620804QZC
RT4G150-1LG1657E	5962-1620808QZC
RT4G150-1LG1657EV	-
RT4G150-1LG1657V	5962-1620812VZC
RT4G150-1LG1657PROTO	-



Microsemi Headquarters

One Enterprise, Aliso Viejo,
CA 92656 USA
Within the USA: +1 (800) 713-4113
Outside the USA: +1 (949) 380-6100
Sales: +1 (949) 380-6136
Fax: +1 (949) 215-4996
Email: sales.support@microsemi.com
www.microsemi.com

© 2019 Microsemi. All rights reserved. Microsemi and the Microsemi logo are trademarks of Microsemi Corporation. All other trademarks and service marks are the property of their respective owners.

Microsemi makes no warranty, representation, or guarantee regarding the information contained herein or the suitability of its products and services for any particular purpose, nor does Microsemi assume any liability whatsoever arising out of the application or use of any product or circuit. The products sold hereunder and any other products sold by Microsemi have been subject to limited testing and should not be used in conjunction with mission-critical equipment or applications. Any performance specifications are believed to be reliable but are not verified, and Buyer must conduct and complete all performance and other testing of the products, alone and together with, or installed in, any end-products. Buyer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the Buyer's responsibility to independently determine suitability of any products and to test and verify the same. The information provided by Microsemi hereunder is provided "as is, where is" and with all faults, and the entire risk associated with such information is entirely with the Buyer. Microsemi does not grant, explicitly or implicitly, to any party any patent rights, licenses, or any other IP rights, whether with regard to such information itself or anything described by such information. Information provided in this document is proprietary to Microsemi, and Microsemi reserves the right to make any changes to the information in this document or to any products and services at any time without notice.

Microsemi, a wholly owned subsidiary of Microchip Technology Inc. (Nasdaq: MCHP), offers a comprehensive portfolio of semiconductor and system solutions for aerospace & defense, communications, data center and industrial markets. Products include high-performance and radiation-hardened analog mixed-signal integrated circuits, FPGAs, SoCs and ASICs; power management products; timing and synchronization devices and precise time solutions, setting the world's standard for time; voice processing devices; RF solutions; discrete components; enterprise storage and communication solutions; security technologies and scalable anti-tamper products; Ethernet solutions; Power-over-Ethernet ICs and midspans; as well as custom design capabilities and services. Microsemi is headquartered in Aliso Viejo, California, and has approximately 4,800 employees globally. Learn more at www.microsemi.com.